



4-Bit Bus Switch, Enable Low 1.8V/2.5V/3.3V, High-Bandwidth, Hot Plug

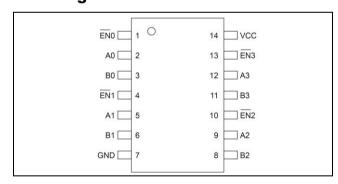
### **Features**

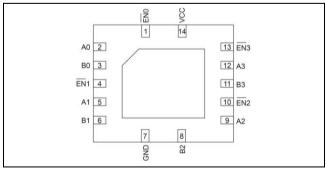
- → Near-Zero propagation delay
- → 5-ohm switches connect inputs to outputs
- → High signal passing bandwidth (500 MHz)
- → Beyond Rail-to-Rail switching:
  - 0 to 5V switching with 3.3V power supply
  - 0 to 3.3V switching with 2.5V power supply
- → 5V I/O tolerant with supply in OFF and ON state
- → 1.8V, 2.5V and 3.3V supply voltage operation
- → Hot Insertion Capable
- → Industrial Operating Temperature: -40°C to +85°C
- → 8kV ESD Protection (human body model)
- → Latch-up Performance: >200mA per JESD17
- → Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- → Halogen and Antimony Free. "Green" Device (Note 3)
- → For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

- → Packaging (Pb-free & Green available):
  - -14-pin TSSOP (L)
  - -14-pin QFN (ZB)

# **Pin Configuration**





# **Description**

The PI3CH400 is a low voltage, 4-channel switch designed with fast individual enables. The switch introduces no additional ground bounce noise or additional propagation delay.

The PI3CH400 device has active low enables. It is very useful in switching signals that have high bandwidth (500 MHz).

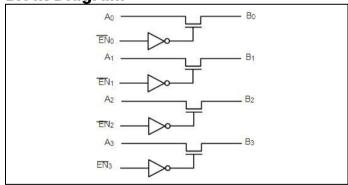
# **Applications**

- → High Bandwidth Data Switching
- → Hot-Docking
- → Analog Signal Switching
- → Differential Signal Switching

# **Pin Description**

Pin No	Pin Name	Description
1, 4, 10	$\overline{\mathrm{EN}}_{0}, \overline{\mathrm{EN}}_{1}, \overline{\mathrm{EN}}_{2}$	Switch Enables
2, 5, 9, 12	A0-A3	A Ports
3, 6, 8, 11	В0-В3	B Ports
14	V <sub>CC</sub>	Power
7	GND	Ground

**Block Diagram** 



### Truth Table<sup>(1)</sup>

$\overline{EN}_x$	Ax	Bx	$V_{CC}$	Function
$X^{(2)}$	Hi-Z	Hi-Z	GND	Disconnect
Н	Hi-Z	Hi-Z	$V_{CC}$	Disconnect
L	Bx	Ax	$V_{CC}$	Connect
T 4				

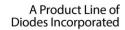
#### Note:

- 1. H=High Voltage Level; L=Low Voltage Level; Hi-Z=High Impedance
- 2. A pull-up resistor should be provided for power-up protection

#### Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.







# **Maximum Ratings**

Storage Temperature	65°C to +150°C
Ambient Temperature with Power Applied	
Supply Voltage to Ground Potential	-0.5V  to + 4.6V
DC Input Voltage	-0.5V  to + 6.0V
DC Output Current	120mA
Power Dissipation	0.5W
l	

#### Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

# **DC Electrical Characteristics**

3.3V supply (Over operating range,  $T_A = -40 \sim +85^{\circ}\text{C}$ ,  $V_{CC} = 3.3\text{V} \pm 10\%$ , unless otherwise noted)

Symbol	Description	Test Conditions <sup>(1)</sup>	Min	Typ <sup>(2)</sup>	Max	Unit
$V_{IH}$	Control Input HIGH Voltage	Guaranteed Logic HIGH Level	2.0	-	-	V
$V_{\rm IL}$	Control Input LOW Voltage	Guaranteed Logic LOW Level	-0.5	-	0.8	V
V <sub>IK</sub>	Clamp Diode Voltage	$V_{CC} = Min., I_{IN} = -18mA$	-	-1.3	-1.8	V
$I_{IH}$	Input HIGH Current	$V_{CC} = Max., V_{IN} = V_{CC}$	-	-	±1	μΑ
$I_{IL}$	Input Low Current	$V_{CC} = Max., V_{IN} = GND$	-	-	±1	μΑ
$I_{OZH}$	High-Impedance Current	$0 \le A, B \le V_{CC}$	-	-	±1	μΑ
D	Switch On-Resistance <sup>(3)</sup>	$V_{CC} = Min., V_{IN} = 0.0V$ $I_{ON} = -48mA \text{ or } -64mA$	-	4	6	Ω
$R_{ON}$		$V_{CC} = Min., V_{IN} = 3.6V$ $I_{ON} = -15mA$	-	5	8	72

#### Notes:

- 1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at  $V_{CC}$  = 3.3V,  $T_A$  = 25°C ambient and maximum loading.
- 3. Measured by the voltage drop between A and B pin at indicated current through the switch. On-Resistance is determined by the lower of the voltages on the two (Ax, Bx) pins.

2.5V supply (Over operating range,  $T_A = -40 \sim +85^{\circ}\text{C}$ ,  $V_{CC} = 2.5\text{V} \pm 10\%$ , unless otherwise noted)

Symbol	Description	Test Conditions <sup>(1)</sup>	Min	Typ <sup>(2)</sup>	Max	Unit
$V_{\mathrm{IH}}$	Control Input HIGH Voltage	Guaranteed Logic HIGH Level	1.8	-	V <sub>CC</sub> +0.3	V
$V_{\rm IL}$	Control Input LOW Voltage	Guaranteed Logic LOW Level	-0.3	-	0.8	V
V <sub>IK</sub>	Clamp Diode Voltage	$V_{CC} = Max., I_{IN} = -6mA$	-	-0.7	-1.8	V
$I_{IH}$	Input HIGH Current	$V_{CC} = Max., V_{IN} = V_{CC}$	-	-	±1	μΑ
${ m I}_{ m IL}$	Input Low Current	$V_{CC} = Max., V_{IN} = GND$	-	-	±1	μΑ
$I_{OZH}$	High-Impedance Current	$0 \le A, B \le V_{CC}$	-	-	±1	μΑ
D	Switch On-Resistance <sup>(3)</sup>	$V_{CC} = Min., V_{IN} = 0.0V$ $I_{ON} = -48mA$	-	4	8	Ω
$R_{ON}$		$V_{CC} = Min., V_{IN} = 2.25V$ $I_{ON} = -15mA$	-	7	14	52

#### Notes:

- 1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at  $V_{CC} = 2.5V$ ,  $T_A = 25$ °C ambient and maximum loading.
- 3. Measured by the voltage drop between A and B pin at indicated current through the switch. On-Resistance is determined by the lower of the voltages on the two (Ax, Bx) pins.



# A Product Line of Diodes Incorporated



PI3CH400

1.8V supply (Over operating range,  $T_A = -40 \sim +85^{\circ}\text{C}$ ,  $V_{CC} = 1.8\text{V} \pm 10\%$ , unless otherwise noted)

Symbol	Description	Test Conditions <sup>(1)</sup>	Min	Typ <sup>(2)</sup>	Max	Unit
$V_{IH}$	Control Input HIGH Voltage	Guaranteed Logic HIGH Level	1.2	-	V <sub>CC</sub> +0.3	V
$V_{\rm IL}$	Control Input LOW Voltage	Guaranteed Logic LOW Level	-0.3	-	0.6	V
$V_{IK}$	Clamp Diode Voltage	$V_{CC}$ = Min., $I_{IN}$ = -18mA	-	-0.7	-1.8	V
$I_{ m IH}$	Input HIGH Current	$V_{CC} = Max., V_{IN} = V_{CC}$	-	ı	±1	μΑ
${ m I}_{ m IL}$	Input Low Current	$V_{CC} = Max., V_{IN} = GND$	1	ı	±1	μΑ
$I_{OZH}$	High-Impedance Current	$0 \le A, B \le V_{CC}$	-	-	±1	μΑ
$R_{ON}$	Switch On-Resistance <sup>(3)</sup>	$V_{CC} = Min., V_{IN} = 0.0V$ $I_{ON} = -48mA$	-	4	8	Ω
NON		$V_{CC} = Min., V_{IN} = 1.6V$ $I_{ON} = -15mA$	-	10	25	22

#### Notes:

- 1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at  $V_{CC}$  = 1.8V,  $T_A$  = 25°C ambient and maximum loading.
- 3. Measured by the voltage drop between A and B pin at indicated current through the switch. On-Resistance is determined by the lower of the voltages on the two (Ax, Bx) pins.

**Capacitance** (T<sub>A</sub> = 25°C, f=1MHz)

Symbol <sup>(1)</sup>	Description	Test Conditions	Typ <sup>(2)</sup>	Unit
$C_{IN}$	Input Capacitance		2.0	
C <sub>OFF</sub>	A/B Capacitance, Switch Off	$V_{IN} = 0V$	3.5	pF
C <sub>ON</sub>	A/B Capacitance, Switch On		7.0	

#### Note:

1. These parameters are determined by device characterization but are not production tested

**Power Supply Characteristics** 

	Symbol	Description	Test Conditions <sup>(1)</sup>	Min	Тур	Max	Unit
Ī	$I_{CC}$	Quiescent Power Supply Current	$V_{CC} = 3.6V$ , $V_{IN} = GND$ or $V_{CC}$	-	0.2	0.5	mA

### Note:

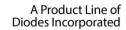
- 1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.
- 2. Typical values are at +25°C ambient

# **Dynamic Electrical Characteristics**

(Over Operating Range,  $T_A = -40 \sim +85^{\circ}\text{C}$ ,  $V_{CC} = 3.3 \text{V} \pm 10\%$ )

Symbol	Description	Test Conditions	Min	Тур	Max	Unit
$X_{TALK}$	Crosstalk	10MHz	-	-60	-	dB
$O_{IRR}$	Off-Isolation	10MHz	-	-60	-	uБ
BW	-3dB Bandwidth	See test Diagram	-	500	-	MHz







### **Switch Characteristics**

Over 3.3V Operating Range

Symbol	Description	Test Conditions <sup>(1)</sup>	Min	Тур	Max	Unit
$t_{\rm PLH}, t_{\rm PHL}$	Propagation Delay <sup>(2, 3)</sup> Ax to Bx, Bx to Ax	See test Diagram	-	-	0.3	
$t_{PZH,} t_{PZL}$	Enable Time $\overline{ENx}$ to Ax or Bx	See test Diagram	1.5	-	9.0	ns
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Disable Time ENx to Ax or Bx	See test Diagram	1.5	-	9.0	

#### Note:

- 1. See test circuit and waveforms.
- 2. This parameter is guaranteed but not tested on Propagation Delays.
- 3. The switch contributes no propagation delay other than the RC delay of the On-Resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.30ns for 10pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the switch when used in a system is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

Over 2.5V Operating Range

Symbol	Description	Test Conditions <sup>(1)</sup>	Min	Тур	Max	Unit
$t_{PLH,} t_{PHL}$	Propagation Delay <sup>(2, 3)</sup> Ax to Bx, Bx to Ax	See test Diagram	-	1	0.3	
t <sub>PZH</sub> , t <sub>PZL</sub>	Enable Time $\overline{EN}x$ to Ax or Bx	See test Diagram	1.5	-	15.0	ns
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Disable Time $\overline{\overline{ENx}}$ to Ax or Bx	See test Diagram	1.5	-	12.0	

#### Note:

- 1. See test circuit and waveforms.
- 2. This parameter is guaranteed but not tested on Propagation Delays.
- 3. The switch contributes no propagation delay other than the RC delay of the On-Resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.30ns for 10pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the switch when used in a system is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

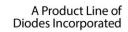
Over 1.8V Operating Range

Symbol	Description	Test Conditions <sup>(1)</sup>	Min	Тур	Max	Unit
$t_{PLH,}t_{PHL}$	Propagation Delay <sup>(2, 3)</sup> Ax to Bx, Bx to Ax	See test Diagram	-	ı	0.3	
$t_{PZH,} t_{PZL}$	Enable Time $\overline{EN}x$ to Ax or Bx	See test Diagram	1.5	-	25.0	ns
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Disable Time $\overline{ENx}$ to Ax or Bx	See test Diagram	1.5	-	12.0	

#### Note:

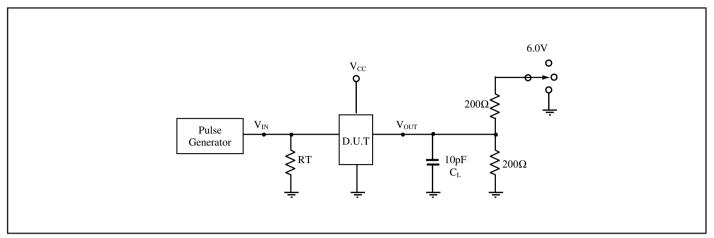
- 1. See test circuit and waveforms.
- 2. This parameter is guaranteed but not tested on Propagation Delays.
- 3. The switch contributes no propagation delay other than the RC delay of the On-Resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.30ns for 10pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the switch when used in a system is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.







# **Test Circuit for Electrical Characteristics**



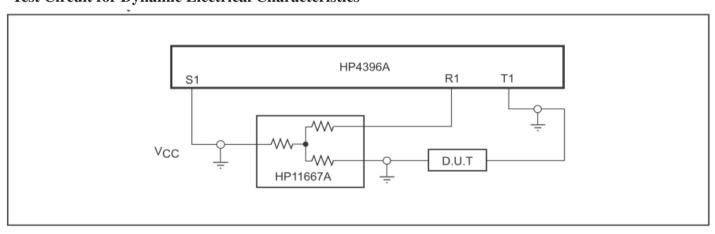
### **Notes:**

- 1.  $C_L$  = Load capacitance: includes jig and probe capacitance.
- 2. RT = Termination resistance: should be equal to ZOUT of the Pulse Generator
- 3. All input impulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O$  = 50-ohm,  $t_R \leq$  2.5ns,  $t_F \leq$  2.5ns.
- 4. The outputs are measured one at a time with one transition per measurement.

# **Switch Positions**

Test	Switch
t <sub>PLZ</sub> , t <sub>PZL</sub>	6.0V
t <sub>PHZ</sub> , t <sub>PZH</sub> .	GND
Prop Delay	Open

# **Test Circuit for Dynamic Electrical Characteristics**

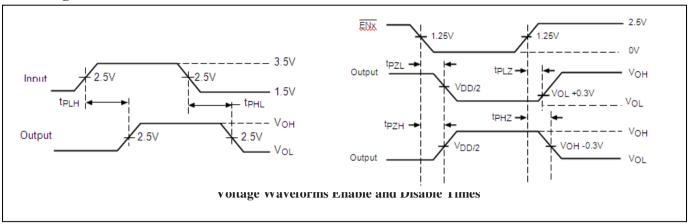








# **Switching Waveforms**



# **Applications Information**

### **Logic Inputs**

The logic control inputs can be driven up to 3.6V regardless of the supply voltage. For example, given a +3.3V supply, EN maybe driven LOW to 0V and HIGH to 3.6V. Driving EN Rail-to-Rail minimizes power consumption.

#### **Hot Insertion**

For Datacom and Telecom applications that have ten or more volts passing through the backplane, a high voltage from the power supply may be seen at the device input pins during hot insertion. The PI3CH400 devices have maximum limits of 6V and 120mA for 20ns. If the power is higher or applied for a longer time or repeatedly reaches the maximum limits, the devices can be damaged.

Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd.

# **Part Marking**

ZB Package



YYWW: Date Code (Year & Workweek)

J: Assembly Site Code G: Wafer Fab Site Code L Package

PĪ3CH 400LE ZYWXX

Z: Fixed Code

0

Y: Date Code (Year)

W: Date Code (Workweek)

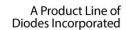
1st X: Assembly Site Code

2nd X: Fab Site Code

Bar above "I" means Fab3 of MGN

Bar above fab code means Cu wire

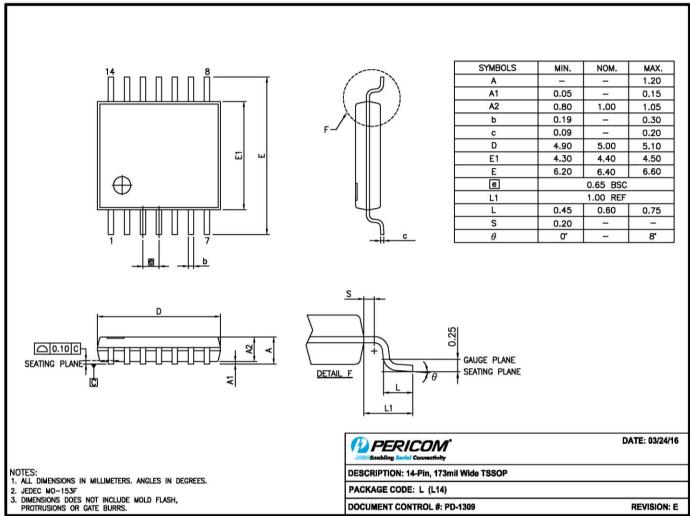






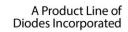
# **Packaging Mechanical**

14-TSSOP (L)



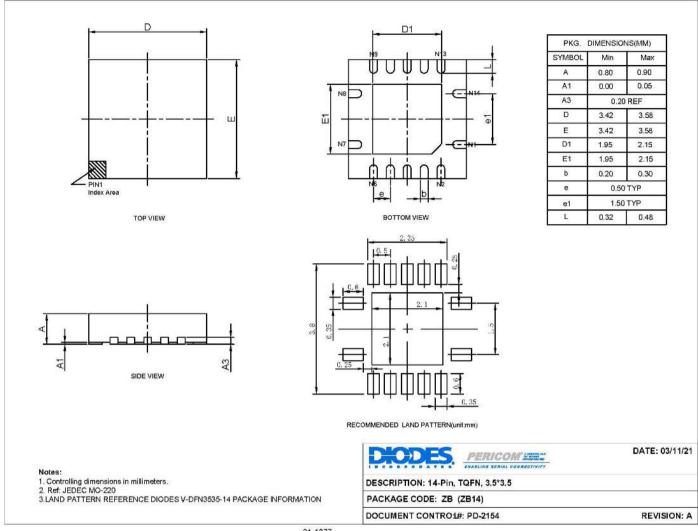
16-0060







### 14-Pin QFN (ZB)



21-1377

For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

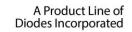
# **Ordering Information**

Part Number	Package Cede	Package Description
PI3CH400LEX	L	14-Pin, 173mil Wide (TSSOP)
PI3CH400ZBEX	ZB	14-Pin, 3.5x3.5 (TQFN)
PI3CH400ZBEX-13R	ZB	14-Pin, 3.5x3.5 (TQFN), Pin 1 orientation is Top

### Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. E = Pb-free and Green
- 5. X suffix = Tape/Reel
- 6. For packaging detail, go to our website at: https://www.diodes.com/assets/MediaList-Attachments/Diodes-Package-Information.pdf







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